

#### US007241704B1

# United States Patent

Wu et al.

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- (54) METHODS FOR PRODUCING LOW STRESS POROUS LOW-K DIELECTRIC MATERIALS USING PRECURSORS WITH ORGANIC FUNCTIONAL GROUPS
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- (\*) Notice: Subject to any disclaimer, the term of this patent is extended or adjusted under 35 U.S.C. (154(b) by 113 days.
- (21) Appl. No.: 10/927,777
- (22) Filed: Aug. 27, 2004

# Related U.S. Application Data

- (63) Continuation-in-part of application No. 10/672,311, filed on Sep. 26, 2003, which is a continuation-in-part of application No. 10/404,593, filed on Mar. 31, 2003.
- (51) Int. Cl.

  ### (2006.01)

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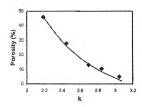
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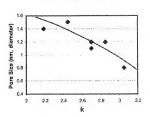
#### (Continued)

Primary Examiner...M. Wikezewski (74) Attorney, Agent, or Firm...Beyer Weaver LLP

## (57) ABSTRACT

Methods of preparing a low stress porous low-k dielectric material on a substrate are provided. The methods involve the use of a structure former precursor and/or porogen precursur with one or more organic functional groups. In some cases, the structure former precursor has carbonearbon double or triple bonds. In other cases, one or both of the structure former precursor and porogen precursor has one or more bulky organic groups. In other cases, the structure former precursor has carbon-carbon double or triple hands and one or both of the structure former precursor and porogen precursor has one or more bulky organic groups. Once the precursor film is formed, the porogen is nemoved, leaving a porous low-k dielectric metrix with high mechanical strength. Different types of structure former precursors and porogen precursors are described. The resulting low stress low-k porous film may be used as a low-k dielectric film in integrated circuit manufacturing applications.

## 30 Claims, 7 Drawing Sheets





#### US 20070093078A

# (19) United States

# (12) Patent Application Publication (10) Pub. No.: US 2007/0093078 A1 Harada et al. (43) Pub. Date: Apr. 26, 2007

(54) POROUS INSULATING FILM, METHOD FOR PRODUCING THE SAME, AND SEMICONDUCTOR DEVICE USING THE SAME

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(21) Appl. No.: 19/580,686

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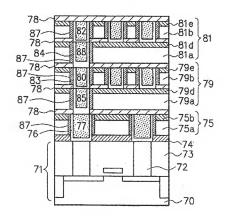
§ 371(c)(1), (2), (4) Date: May 25, 2886 (30) Foreign Application Priority Data

(51) Int. Cl.

H01L 21/31 (2006.01) H01L 21/469 (2006.01) (52) U.S. Cl. 438/796

## (57) ABSTRACT

The present invention provides a process of producing a prorus insulating film effective as an insulating film constituting a semiconductor device and a process of producing a perorus ansalating film having high adhesion to a semiconductor material, which is in contact with the upper and lower interfaces of the insulating film. Give containing molecule support of a less one or more organic silica composatis, which have a cyclic silica skeleton in its molecule and have at least one or one unsamated hydrocarchos groups bound with the cyclic silica skeleton is introduced into plasma grow a procus insulating film on a semiconductor substrate.





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Patents Trademarks Other Patent eBusiness - 0 Patent Application Information Retrieval \* Electronic florus Order Carbines Absolutation As Filed Order Carbined File Wrepper 🂥 Mishi Crist List. \* Patent Application information (PATR) METHOD FOR FORMING INSULATION FILM AND APPARATUS FOR FORMING 10/703 092 NSULATION FILM \* Pacent Ownership % fees mage File Wrapper # Supplemental Resources & Support This application is officially maintained in electronic form, To View; Click the desired Document Description. To Download and Print: Check the desired document(s) and click Start Download. Patent Information Available Documents Patent Guidance and General Info Document Page Count # Codes\_ kulss\_& Manuals Document Mail Room Date Start Downsoud N Employee & Office Directories Code It Description 11 At Assources & Aubic Rouices 04-21-2010 PETDEC Petition Decision Required for FTA Patent Searches PET.PTA.RCAL (ecalculation at view 04-09-2010 1 Patent Official Georgite \* Search Patients & Applications of Wyeth fi Search Biological Sequences 04-09-2010 N417 Acknowledgment 2 El Cosses. Products & Sendons Receipt 09-23-2099 ISSUE NTF base Notrication 1 Issue Fee Exement (PTD-SEB) Convocate 08-31-2009 IFEE 4 Trademarks Policy & Law Fee Worksneet RECORDS 08-31-2009 WEEE 2 SES 08-31-2009 N417 Adengydesigmest 2 Receipt Netice of Allowance 06-18-2009 ACM and Eres Due 4 (PTOL: 85) 06-18-2009 **FWCLM** Index of Claims (\*) Search information mahating 06-18-2009 SREW classification. 1 databases and other search related notes Issue Information including classification. 06-18-2009 **HFVV** m signatulosc..nages. claim, recomberno, Amendment/Seq. Reconsideration: 05-18-2009 A... Alter Non-Final Retect 05-18-2009 CLM Glains 8 4 Applicant 05-18-2009 REM Acoumers s/Remarks 8 6 Missie in an Amendment Egg. Workshoot 05-18-2009 WEEE 2 05-18-2009 1417 2 Acknowledgment Patent Authoritemico.for 85,18,2009 136A Extension of Time alt regises Examiner Interview 05-06-2009 EXIN Suremery Record 3 (PTOL - 413) 12,17,2008 CINE Non-Final Rejection List of references 12-17-2008 892 oted by examiner 12-17-2008 **PWCLM** Index of Claims Search information enclading

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